



WMM7018ABVS0

Bottom port analog silicon Microphone

Descriptions

The WMM7018ABVS0 is a miniature, high performance, low power, bottom port silicon microphone.

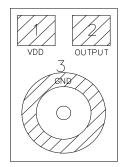
The WMM7018ABVS0 consists of an acoustic sensor, a low noise input buffer, and an output amplifier.

These devices are suitable for portable electronic devices where excellent wideband audio performance and RF immunity are required applications.

The WMM7018ABVS0 is manufactured in a compact 2.75mm*1.85mm*0.90mm, 3-pin package.



Product appearance



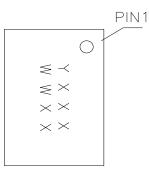
Features

- Small package
- Low current
- Flat Frequency Response
- Zero-Height
- Ultra-Stable Performance
- Standard SMD Reflow
- Omnidirectional

Applications

- TWS Earphone
- Wireless Headsets
- Smart Speakers
- Wearable Electronics
- Portable Electronics
- Smart Home Electronics

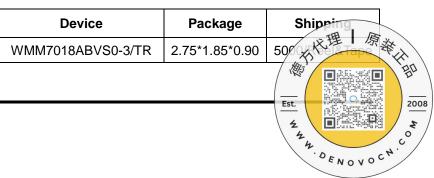
Pin configuration (Bottom view)



Marking (Top view)

Y = Year code WW = Week code X X X = Batch code

Order information





Absolute Maximum Ratings

Parameter	Absolute Maximum Rating	Units
Supply voltage	4.2	V
Operation temperature range	-40~85	°C
Storage temperature range	-40 to +100	°C

Stresses at the maximum ratings shown in Table 1 may cause permanent damage to the device. These are stress ratings only at which the device may not function when an operation at these or any other condition beyond those specified under "Electro-Acoustic Specifications".

Acoustic & Electrical Specifications

Test condition:+25±2°C,60%~70% RH,86~106Kpa, Vdd=2.75V, no load, unless otherwise specified.

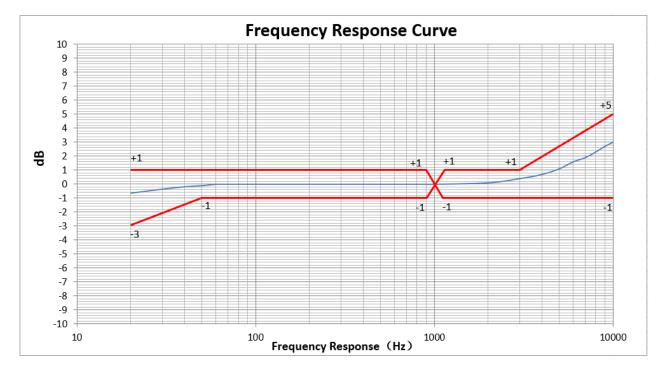
Parameter	Symbol	Conditions	Min	Тур	Max	Units
Supply Voltage	VDD		1.6	2	3.6	V
Supply Current	IDD		-	120	200	uA
Sensitivity	S	94dB SPL @1kHz	-39	-38	-37	dBv
Signal to Noise Ratio	SNR	f=1kHz, BW=20-20kHz, A-Weighted		63		dB(A)
Total Harmonic Distortion	THD	94dB SPL @1kHz, S=Typ,	-	0.2	0.5	%
Acoustic Overload Point	AOP	10%THD @1kHz	-	127	-	dBSPL
Power Supply Rejection	PSR	100mVpp 7/8 duty cycle rectangular wave @217Hz, A-weight	-	-102	-	dBv
Power Supply Rejection Ratio	PSRR	200 mVpp sinewave @ 1 kHz	-	71	-	dB
DC Output			-	0.85	-	V
Output impedance	ZOUT	@1kHz	-	-	400	Ω
Directivity			Omnidirectional			

Note: Frequency response, sensitivity and current consumption are tested by 100% on product line.

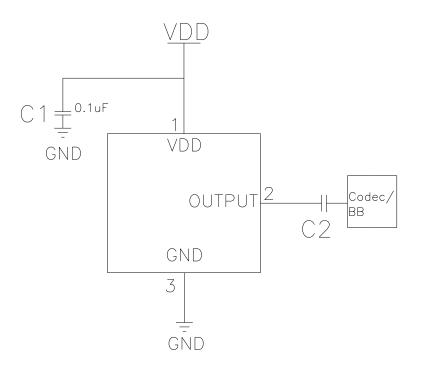




Frequency Response Curve



Application information



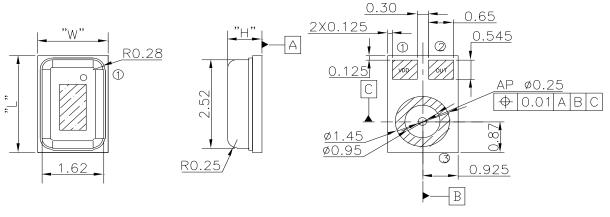
Note:

- All GND pins must be connected to ground.
- Capacitors near the microphone should not contain Class 2 dielectrics.



NII SEMI

Mechanical Specification



TOP View

Side View

Bottom View

ltem	Dimension	Tolerance
Length(L)	2.75	±0.10
Width(W)	1.85	±0.10
Height(H)	0.90	±0.10
Acoustic Port (AP)	Ø0.25	±0.05

Pin#	Pin Name	Description
1	VDD	Power Supply
2	OUTPUT	Output Signal
3	GND	GND

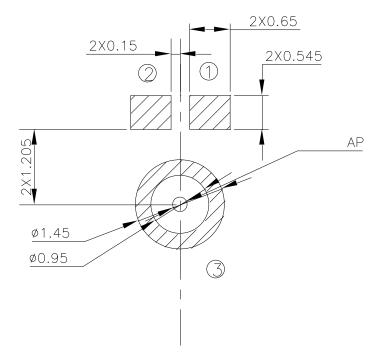
Notes:

- Dimensions are in millimeters unless otherwise specified.
- \bullet Tolerance is ±0.10mm unless otherwise specified.

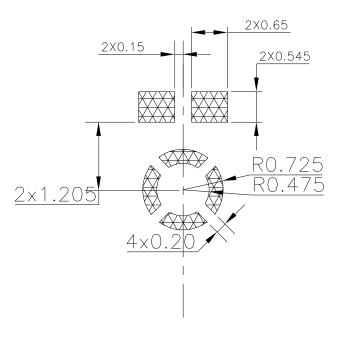


NII SEMI

Example Land Pattern



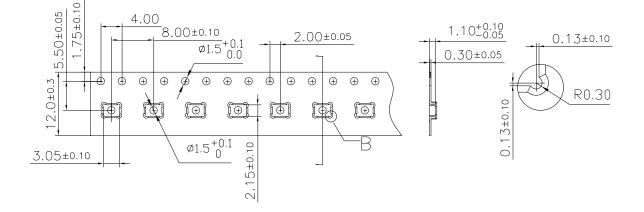
Example Solder Stencil Pattern

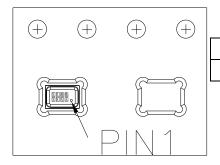




III SEMI

Packaging & Marking Detail





Model Number	Reel Diameter	Quantity Per Reel
WMM7018ABVS0	13"	5,000

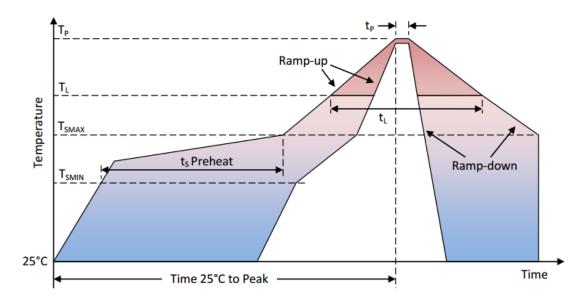
Notes:

- Dimensions are in millimeters unless otherwise specified.
- Vacuum pickup only in the pick area indicated in Mechanical Specifications.
- Tape & reel per EIA-481.
- Labels applied directly to reel and external package.





Referenced Reflow Profile



Profile Feature	Pb-Free
Average Ramp-up rate (TSMAX to TP)	3°C/second max.
Preheat • Temperature Min (Тsміn)	150°C
 Temperature Max (Tsmax) Time (Tsmin to Tsmax) (ts) 	200°C 60-180 seconds
Time maintained above: • Temperature (TL) • Time (tL)	217°C 60-150 seconds
Peak Temperature (TP)	260°C
Time within 5°C of actual Peak Temperature (tP)	20-40 seconds
Ramp-down rate (TP to TSMAX)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max

Note:

All temperatures refer to topside of the package, measured on the package body surface.



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Additional Notes

- (A) Maximum of 3 reflow cycles is recommended.
- (B) In order to minimize device damage:
 - Do not board wash or clean after the reflow process.
 - Do not brush board with or without solvents after the reflow process.
 - Do not directly expose to ultrasonic processing, welding, or cleaning.
 - Do not insert any object in port hole of device at any time.
 - Do not apply over 30 psi of air pressure into the port hole.
 - Do not pull a vacuum over port hole of the microphone.

• Do not apply a vacuum when repacking into sealed bags at a rate faster than 0.5 atm/sec.

Materials Statement

Meets the requirements of the European RoHS and Halogen-Free.

Test	Description
Thermal Shock	100 cycles air-to-air thermal shock from -40°C to +125°C with 15 minute soaks.
High Temperature Storage	1000 hours at +105°C environment
Low Temperature Storage	1000 hours at -40°C environment
High Temperature Bias	1000 hours at +105°C under bias.
Low Temperature Bias	1000 hours at -40°C under bias.
Temperature / Humidity Bias	1000 hours at +85°C /85% R.H.
Vibration	4 cycles of 20 to 2,000 Hz sinusoidal sweep with 20g peak acceleration lasting 12 minutes in X, Y, and Z directions.
ESD-HBM	3 discharges of ±2 kV direct contact to I/O pins.
ESD-LID/GND	3 discharges of ±8 kV direct contact to lid while unit is grounded.
ESD-MM	3 discharges of ±200V direct contact to I/O pins.
Reflow	5 reflow cycles with peak temperature of +260°C
Mechanical Shock	3 pulses of 10,000g in the X, Y, and Z direction
Drop Test To be no interference in operation after dropped to marble 1.0cm steel plate 18 times from 1.5 meter height.	

Reliability Specifications

Note:

After reliability tests are performed, the sensitivity of the microphones shall not deviate more than from its initial value from its initial value.